This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claim 1 (Currently Amended): Coated tool[[,]] in particular for machining, having said coated

tool comprising a substrate[[,]] which has having a predetermined coefficient of thermal

expansion, a first carbon layer which is deposited on the substrate, which said first carbon layer

has a predetermined highly predominant fraction of 80-100% of carbon with a diamond crystal

structure and a coefficient of thermal expansion which is smaller than the coefficient of thermal

expansion of the substrate; and at least one second carbon layer (B), which is deposited and

spaced from further outside with reference to the substrate (M) than by at least the first carbon

layer (A), and in the case of which the wherein said second carbon layer has a fraction of carbon

with a crystal diamond crystal structure is highly predominant which is 80-100% but lower than

the predetermined fraction of carbon with a crystal diamond structure in the first carbon layer

(A), and in the case of which the wherein said second carbon layer has a coefficient of thermal

expansion that is greater than the coefficient of thermal expansion of the first carbon layer, and

said (A), characterized in that the second carbon layer includes consists of nano-crystalline

diamond.

Claim 2. Cancelled.

Claim 3. (Currently Amended) Tool according to Claim 1[[,]] characterized in that wherein the

second carbon layer (B) is deposited directly on the first carbon layer (A).

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Claim 4. (Currently Amended) Tool according to Claim 1[[,]] characterized in that formed further comprising an interlayer positioned between the first carbon layer (A) and the second carbon layer (B) is an interlayer in the case of which, and wherein the fraction of carbon with a diamond crystal structure drops continuously from the first carbon layer (A) in the direction of the second carbon layer (B).

Claim 5. (Currently Amended) Tool according to Claim 1[[,]] characterized in that it has an wherein an overall thickness of the first carbon layer (A) and the second carbon layer (B) in the range from is about 1 to 40 µm.

Claim 6. (Currently Amended) Tool according to Claim 5[[,]] characterized in that it has an overall thickness of the first carbon layer (A) and the second carbon layer (B) in the range of is <u>about</u> 4 to 20 μm.

Claim 7. (Currently Amended) Tool according to Claim 6[[,]] characterized in that an wherein the overall thickness of the first carbon layer (A) and of the second carbon layer (B) in the range ef is about 6 to 15 µm is formed.

Claim 8. (Currently Amended) Tool according to Claim 1[[,]] eharacterized in that wherein the second carbon layer (B) has a minimum thickness of 0.5 µm.

Claim 9. (Currently Amended) Tool according to one of Claims 8, characterized in that further material layers are claim 8 further comprising at least one layer of a material arranged between the first carbon layer and the second carbon layer.

Claim 10. (Currently Amended) Tool according to Claim 1, characterized in that with reference to the substrate beyond the second carbon layer futher material further comprising at least one Appln. No.: 09/937,897

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layer of a material spaced from said substrate by at least said second carbon layer layers are arranged.

Claim 11. (Currently Amended) Process for producing a tool substrate which is coated with carbon and has a predetermined coefficient of thermal expansion, said process comprising the steps of having the following steps:

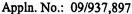
depositing a first carbon layer onto the tool substrate (M) a first carbon layer (A) [[,]] the and selecting process conditions being selected such that the first carbon layer (A) contains a predetermined highly predominant fraction of carbon with a diamond crystal structure and has a smaller coefficient of thermal expansion than the tool substrate (M); and

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b)

depositing a second carbon layer such that at least said first carbon layer separates said second carbon layer and said substrate (B), which lies further outside with reference to the substrate (M) than the first carbon layer (A)[[,]] the and selecting process conditions being selected in such a way that by contrast with the predetermined fraction of carbon with a diamond crystal structure of the first carbon layer (A) the second carbon layer (B) has a highly predominant but reduced proportion of carbon with a diamond crystal structure relative to the predetermined fraction of carbon with a diamond structure of the first layer, and a larger coefficient of thermal expansion that than the first carbon layer (A) and consists of nanocrystalline diamond.

Claim 12. (Currently Amended) Process according to Claim 11, wherein in which in step a) the process conditions are selected such that the first carbon layer (A) has a high as possible a fraction of carbon with diamond crystal structure.



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Claim 13. (Currently Amended) Process according to Claim 11[[,]] wherein in which in step b) the process conditions of step a) are changed to reduce the fraction of carbon with a diamond crystal structure by comparison with the first carbon layer (A).

Claim 14. (Currently Amended) Process according to Claim 12[[,]] wherein in which in step b) the process conditions of step a) are changed to reduce the fraction of carbon with a diamond crystal structure by comparison with the first carbon layer (A).

Claim 15. (Currently Amended) Tool according to Claim 2[[,]] wherein characterized in that the second carbon layer (B) is deposited directly on the first carbon layer (A).

Claim 16. (Currently Amended) Tool according to Claim 2[[,]] eharacterized in that formed further comprising an interlayer positioned between the first carbon layer (A) and the second carbon layer (B) is an interlayer in the case of which, and wherein the fraction of carbon with a diamond crystal structure drops continuously from the first carbon layer (A) in the direction of the second carbon layer (B).

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Claim 17. (Currently Amended) Tool according to Claim 2[[,]] characterized in that it has an wherein an overall thickness of the first carbon layer (A) and the second carbon layer (B) in the range from is about 1 to 40 µm.

Claim 18. (Currently Amended) Tool according to Claim 3 characterized in that it has an wherein an overall thickness of the first carbon layer (A) and the second carbon layer (B) in the range from is about 1 to 40 µm.

Claim 19. (Currently Amended) Tool according to Claim 2[[,]]-characterized in that wherein the second carbon layer (B) has a minimum thickness of 0.5 µm.

Claim 20. (Currently Amended) Tool according to Claim 3[[,]] characterized in that wherein the second carbon (B) has a minimum thickness of 0.5 µm.